Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	l:
Metal	
Overall Length:	
2.500 inches	
Overall Height:	
0.670 inches	
Overall Width:	
0.890 inches	
Function For Wh	ich Designed:
Transient suppres	sor
End Application:	
F16aircombfit 817	55
Mounting Facility	Quantity:
2	
Mounting Metho	l:
Unthreaded hole	
Features Provide	d:
Hermetically seale	d case
Semiconductor N	laterial:
Silicon	
Voltage Rating Ir	Volts Per Characteristic:
31.5 reverse volta	ige, dc
Current Rating P	er Characteristic:
500.00 milliamper	es forward current, average peak
Power Rating Pe	r Characteristic:
10.0 watts small-s	ignal input power, common-collector preset
Maximum Operat	ing Tempurature Per Measurement Point:
175.0 degrees cel	sius ambient air
Test Data Docum	ent:
81755-c8943 drav	ving (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any spec	ification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type A	nd Quantity:
2 turret	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	